imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

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General purpose transistors (dual transistors) EMX26

Features

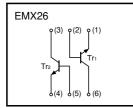
- 1) Two 2SD2654 chips in a EMT package.
- 2) Mounting possible with EMT3 automatic mounting machines.
- 3) Transistor elements are independent, eliminating interference.
- 4) Mounting cost and area can be cut in half.

Structure

Epitaxial planar type NPN silicon transistor

The following characteristics apply to both Tr1 and Tr2.

Equivalent circuit

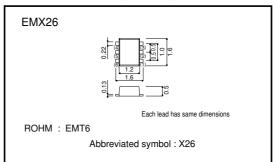


| Parameter | Symbol | Limits | Unit | | | |
|---------------------------|--------|----------------|--------------|--|--|--|
| Collector-base voltage | Vсво | 60 | V | | | |
| Collector-emitter voltage | VCEO | 50 | V | | | |
| Emitter-base voltage | VEBO | 12 | V | | | |
| Collector current | lc | 0.15 | A (DC) | | | |
| | IC | 0.2 | A (Pulse) *1 | | | |
| Power dissipation | Pd | 150 (TOTAL) | mW *2 | | | |
| Junction temperature | Tj | 150 | °C | | | |
| Storage temperature | Tstg | –55 to +150 °C | | | | |
| | | | | | | |

•Absolute maximum ratings (Ta=25°C)

*1 Single pulse Pw=100ms.*2 120mW per element must not be exceeded.

•External dimensions (Unit : mm)



EMX26

Transistors

Electrical characteristics (Ta=25°C)

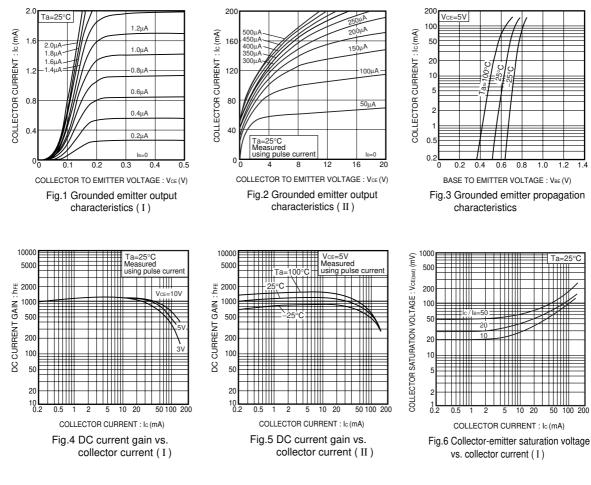
| Parameter | Symbol | Min. | Typ. | Max. | Unit | Conditions | |
|--------------------------------------|----------|------|------|------|------|----------------------------|---|
| Collector-base breakdown voltage | ВУсво | 60 | - | - | V | Ic=10μA | |
| Collector-emitter breakdown voltage | BVCEO | 50 | - | - | V | Ic=1mA | |
| Emitter-base breakdown voltage | BVEBO | 12 | - | - | V | Iε=10μA | |
| Collector cutoff current | Ісво | - | - | 0.3 | μA | Vcb=50V | |
| Emitter cutoff current | Іево | - | - | 0.3 | μA | VEB=12V | |
| Collector-emitter saturation voltage | VCE(sat) | - | - | 0.3 | V | Ic/IB=50mA/5mA | * |
| DC current transfer ratio | hfe | 820 | - | 2700 | - | Vce/lc=5V/1mA | * |
| Transition frequency | fт | - | 250 | - | MHz | Vce=5V, Ie=-10mA, f=100MHz | * |
| Output capacitance | Cob | - | 3.5 | * | pF | VCB=5V, IE=0A, f=1MHz | |

* Measured using pulse current.

Packaging specifications

| | Package | Taping |
|-------|---------------------------------|--------|
| | Code | T2R |
| Туре | Basic ordering unit (pieces) | 8000 |
| EMX26 | | 0 |

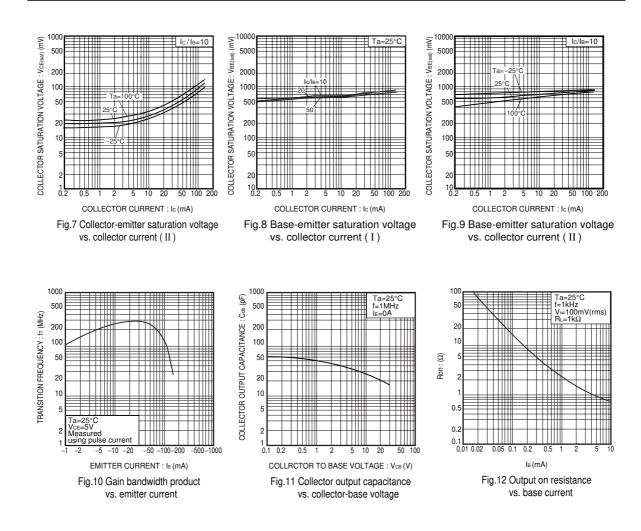
Electrical characteristic curves



ROHM

EMX26

Transistors



ROHM

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